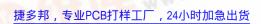
查询DS3896供应商



January 1996

S3896/DS3897 BTL Trapezoidal Transceivers

National Semiconductor

DS3896/DS3897 BTL Trapezoidal[™] Transceivers

General Description

These advanced transceivers are specifically designed to overcome problems associated with driving a densely populated backplane, and thus provide significant improvement in both speed and data integrity. Their low output capacitance, low output signal swing and noise immunity features make them ideal for driving low impedance buses with minimum power consumption.

The DS3896 is an octal high speed schottky bus transceiver with common control signals, whereas the DS3897 is a quad device with independent driver input and receiver output pins. The DS3897 has a separate driver disable for each driver and is, therefore, suitable for arbitration lines. The separate driver disable pins (En) feature internal pull ups and may be left open if not required. On the other hand, the DS3896 provides high package density for data/address lines

The open collector drivers generate precise trapezoidal waveforms, which are relatively independent of capacitive loading conditions on the outputs. This significantly reduces noise coupling to adjacent lines. In addition, the receivers use a low pass filter in conjunction with a high speed comparator, to further enhance the noise immunity and provide equal rejection to both negative and positive going noise pulses on the bus.

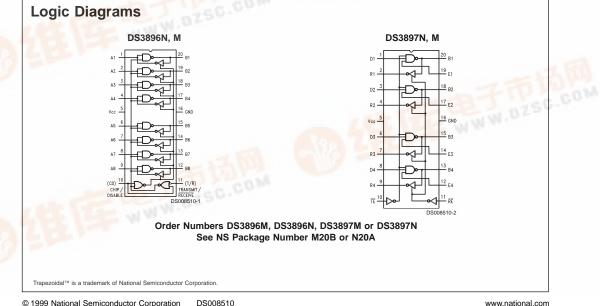
To minimize bus loading, these devices also feature a schottky diode in series with the open collector output that isolates the driver output capacitance in the disabled state. The output low voltage is typically "1V" and the output high level is intended to be 2V. This is achieved by terminating the bus

with a pull up resistor to 2V at both ends. The device can drive an equivalent DC load of 18.5Ω (or greater) in the above configuration.

These signalling requirements, including a 1 volt signal swing, low output capacitance and precise receiver thresholds are referred to as Bus Transceiver Logic (BTL).

Features

- 8 bit DS3896 transceiver provides high package density ■ 4 bit DS3897 transceiver provides separate driver input and receiver output pins
- BTL compatible
- Less than 5 pF output capacitance for minimal bus loading
- 1 Volt bus signal swing reduces power consumption
- -Trapezoidal driver waveforms (t_r, t_f \cong 6 ns typical) reduce noise coupling to adjacent lines
- Temperature insensitive receiver thresholds track the bus logic high level to maximize noise immunity in both high and low states
- Guaranteed A.C. specifications on noise immunity and propagation delay over the specified temperature and supply voltage range
- . Open collector driver output allows wire-or connection
- Advanced low power schottky technology
- Glitch free power up/down protection on driver and receiver outputs
- TTL compatible driver and control inputs and receiver outputs



© 1999 National Semiconductor Corporation

dzsc.com

Absolute Maximum Ratings (Note 1)

.

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage	6V
Control Input Voltage	5.5V
Driver Input and Receiver Output	5.5V
Receiver Input and Driver Output	2.5V
Power Dissipation at 70°C N Package	1480 mW
M Package	TBD mW

Storage Temperature Range	–65°C to +150°C
Lead Temperature (Soldering, 4 sec.)	260°C

Recommended Operating Conditions

	Min	Max	Units
Supply Voltage, V _{CC}	4.75	5.25	V
Bus Termination Voltage	1.90	2.10	V
Operating Free Air Temperature	0	70	°C

Electrical Characteristics: (Notes 2, 3)

 $(0^{\circ}C \leq T_{A} \leq 70^{\circ}C, \, 4.75V \leq V_{CC} \leq 5.25V$ unless otherwise specified)

Symbo	Parameter	Conditions	Min	Тур	Мах	Units
Driver a	Ind Control Inputs: (An, Dn, En, CD, T	/R, RE, TE)				
V _{IH}	Logical "1" Input Voltage		2.0			V
VIL	Logical "0" Input Voltage				0.8	V
I _I	Logical "1" Input Current	$An = Dn = En = V_{CC}$			1	mA
IIH	Logical "1" Input Current	An = Dn = En = 2.4V			40	μΑ
IIHC	Logical "1" Input Current	$CD = T/\overline{R} = \overline{RE} = \overline{TE} = 2.4V$			80	μA
I_{IL}	Logical "0" Input Current	An = Dn = En = 0.4V		-1	-1.6	mA
I _{ILC}	Logical "0" Input Current	$CD = T/\overline{R} = \overline{RE} = \overline{TE} = 0.4V$		-180	-400	μΑ
V _{CL}	Input Diode Clamp Voltage	Iclamp = -12 mA		-0.9	-1.5	V
Driver 0	Dutput/Receiver Input: (Bn)					
V _{OLB}	Low Level Bus Voltage	An = Dn = En = T/\overline{R} = 2V, VL = 2V	0.75	1.0	1.2	V
		RL = 18.5Ω , CD = \overline{TE} = $0.8V$ (<i>Figure 1</i>)				
I _{IHB}	Maximum Bus Current (Power On)	An = Dn = En = 0.8V, V_{CC} = 5.25V		10	100	μΑ
		Bn = 2V				
I _{ILB}	Maximum Bus Current (Power Off)	$An = Dn = En = 0.8V, V_{CC} = 0V$			100	μΑ
		Bn = 2V				
V _{TH}	Receiver Input Threshold	$V_{\rm CC} = 5V$	1.47	1.55	1.62	V
Receive	r Output: (An, Rn)	·				
V _{он}	Logical "1" Output Voltage	Bn = 1.2V, I _{OH} = -400 μA	2.4	3.2		V
		$CD = T/\overline{R} = \overline{RE} = 0.8V$				
V _{OL}	Logical "0" Output Voltage	Bn = 2V, I _{OL} = 16 mA		0.35	0.5	V
		$CD = T/\overline{R} = \overline{RE} = 0.8V$				
los	Output Short Circuit Current	Bn = 1.2V	-20	-70	-100	mA
		$CD = T/\overline{R} = \overline{RE} = 0.8V$				
I _{cc}	Supply Current (DS3896)	V _{CC} = 5.25V		90	135	mA
I _{cc}	Supply Current (DS3897)	V _{CC} = 5.25V		50	80	mA

Note 1: "Absolute maximum ratings" are those beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the device should be operated at these limits. The table of "Electrical Characteristic" provide conditions for actual device operation.

Note 2: All currents into device pins are positive; all currents out of device pins are negative. All voltages are referenced to device ground unless otherwise specified. Note 3: All typicals are given for V_{CC} = 5V and T_a = 25°C.

DS3896 Switching Characteristics

 $(0^{\circ}C \le T_A \le 70^{\circ}C, 4.75V \le V_{CC} \le 5.25V$ unless otherwise specified)

Symbol	Parameter	Conditions		Min	Тур	Max	Units
Driver:							
t _{DLH}	An to Bn	$CD = 0.8V, T/\overline{R} = 2.0V, VL = 2V$		5	9	15	ns
t _{DHL}			(Figure 2)	5	9	15	ns

Symbol	≤ 70°C, 4.75V ≤ V _{CC} ≤ 5.25 Parameter	Conditions	Min	Тур	Max	Units
Driver:	rarameter	Conditions		Typ	max	01113
t _{DLHC}	CD to Bn	An = T/\overline{R} = 2.0V, VL = 2V	5	10	18	ns
t _{DHLC}		(Figure 2)	5	12	20	ns
t _{DLHT}	T/R to Bn	VCI = An, VC = 5V, (<i>Figure 5</i>)	5	15	25	ns
		$CD = 0.8V, RC = 390\Omega, CL = 30 pF$	5	22	35	ns
DITET		RL1 = 18Ω, RL2 = NC, VL = 2V				
t _R	Driver Output Rise Time	$CD = 0.8V, T/\overline{R} = 2V, VL = 2V$	3	6	10	ns
t _F	Driver Output Fall Time	(Figure 2)	3	6	10	ns
Receiver:						
t _{RLH}	Bn to An	$CD = 0.8V, T/\overline{R} = 0.8V$	5	12	18	ns
t _{RHL}		(Figure 3)	5	10	18	ns
t _{RLZC}	CD to An	Bn = 2.0V, T/R = 0.8V, CL = 5 pF	5	10	18	ns
		$RL1 = 390\Omega$, $RL2 = NC$, $VL = 5V$ (<i>Figure 4</i>)				
t _{RZLC}		Bn = 2.0V, T/R = 0.8V, CL = 30 pF	5	8	15	ns
		RL1 = 390Ω, RL2 = 1.6k, VL = 5V (<i>Figure 4</i>)				
t _{RHZC}		$Bn = 0.8V, T/\overline{R} = 0.8V, VL = 0V,$	2	4	8	ns
		RL1 = 390Ω , RL2 = NC, CL = 5 pF (<i>Figure 4</i>)				
t _{RZHC}		Bn = 0.8V, T/\overline{R} = 0.8V, VL = 0V,	3	7	12	ns
		RL1 = NC, RL2 = 1.6k, CL = 30 pF (<i>Figure 4</i>)				
t _{RLZT}	T/R to An	VCI = Bn, VC = 2V, RC = 18Ω,	5	10	18	ns
		CD = 0.8V, VL = 5V, RL1 = 390Ω,				
		RL2 = NC, CL = 5 pF (<i>Figure 5</i>)				
t _{RZLT}		$VCI = Bn, VC = 2V, RC = 18\Omega,$	14	24	40	ns
		$CD = 0.8V, VL = 5V, RL1 = 390\Omega,$				
		RL2 = 1.6k, CL = 30 pF (<i>Figure 5</i>)				
t _{RHZT}		$VCI = Bn, VC = 0V, RC = 18\Omega,$	2	4	8	ns
		$CD = 0.8V, VL = 0V, RL1 = 390\Omega,$				
		RL2 = NC, CL = 5 pF (Figure 5)				
t _{RZHT}		$VCI = Bn, VC = 0V, RC = 18\Omega,$	2	8	15	ns
		CD = 0.8V, VL = 0V, RL1 = NC				
		RL2 = 1.6k, CL = 30 pF (<i>Figure 5</i>)				
t _{NR}	Receiver Noise	(Figure 6)	3	6		ns
	Rejection Pulse Width					

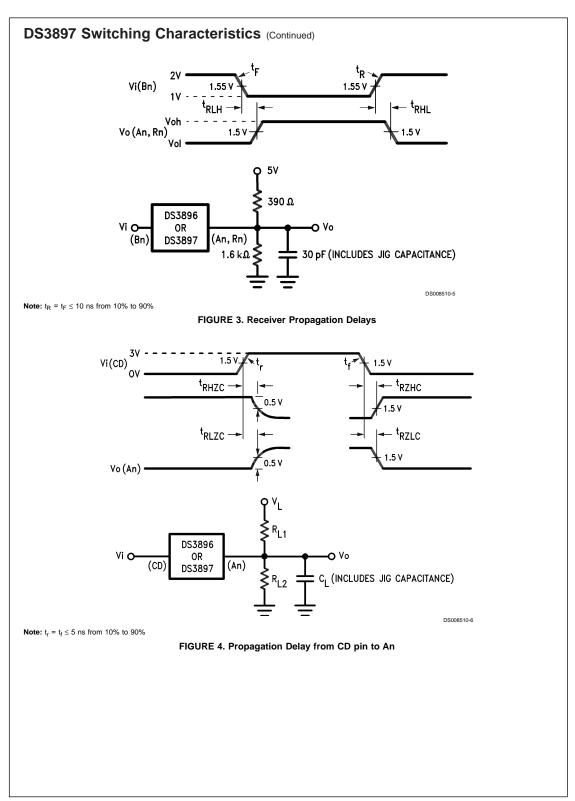
DS3897 Switching Characteristics ($0^{\circ}C \le T_{A} \le 70^{\circ}C$, 4.75V $\le V_{CC} \le 5.25V$ unless otherwise specified)

· ·

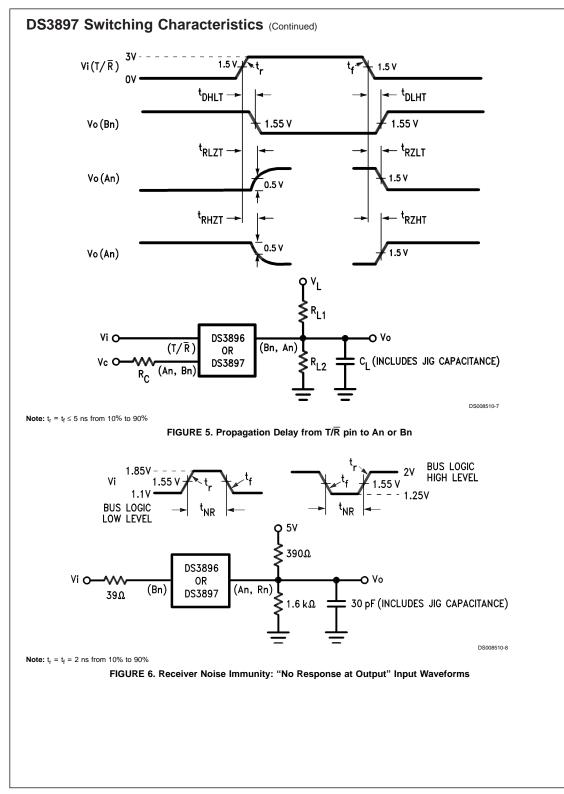
Symbol	Parameter	Conditions	Min	Тур	Max	Units
Driver:						
t _{DLH}	Dn, En to Bn	$\overline{\text{TE}} = 0.8\text{V}, \overline{\text{RE}} = 2.0\text{V}, \text{VL} = 2\text{V}$	5	9	15	ns
t _{DHL}		(Figure 2)	5	9	15	ns
t _{DLHT}	TE to Bn	An = \overline{RE} = 2.0V, VL = 2V, (Figure 2)	5	10	18	ns
t _{DHLT}		RC = 390Ω, VCI = An, VC = 5V, CL = 30 pF	5	12	20	ns
		RL1 = 18Ω , RL2 = NC, VL = 2V (<i>Figure 5</i>)				
t _R	Driver Output Rise Time	$CD = 0.8V, T/\overline{R} = 2V, VL = 2V$	3	6	10	ns
tF	Driver Output Fall Time	(Figure 2)	3	6	10	ns
Receiver:	•					
t _{RLH}	Bn to Rn	$\overline{\text{TE}} = 2.0 \text{V}, \overline{\text{RE}} = 0.8 \text{V}$ (Figure 3)	5	10	18	ns

Symbol	Parameter	Conditions	Min	Тур	Max	Units
Receiver:				71		
RHL			5	12	18	ns
RLZR	RE to Rn	$Bn = \overline{TE} = 2V, VL = 5V, CL = 5 pF$	5	10	18	ns
		RL1 = 390Ω, RL2 = NC (<i>Figure 4</i>)				
RZLR		$Bn = \overline{TE} = 2V, VL = 5V, CL = 30 \text{ pF}$	5	8	15	ns
		RL1 = 390Ω , RL2 = 1.6k (<i>Figure 4</i>)				
RHZR		$Bn = 0.8V, \overline{TE} = 2V, VL = 0V,$	2	4	8	ns
		RL1 = 390Ω , RL2 = NC, CL = 5 pF (<i>Figure 4</i>)				
RZHR		$Bn = 0.8V, \overline{TE} = 2V, VL = 0V,$	3	7	12	ns
		RL1 = NC, RL2 = 1.6k, CL = 30 pF (<i>Figure 4</i>)				
NR	Receiver Noise	(Figure 6)	3	6		ns
	Rejection Pulse Width					
	Receiver:				0.5	
RLH	Dn to Rn	$\overline{\text{TE}} = \overline{\text{RE}} = 0.8 \text{V}$ (Figure 7)	10	20	30	ns
RHL			10	20	30	ns
		DS3896 OR DS3897 (Bn) DS008510-3				
		DS3896 OR DS3897 (Bn) DS3008510-3 FIGURE 1. Driver Output Low Voltage Test				
	Vi (An, Dn, En, t _{DLH} ,	$DS3896 OR OR OVOLD$ $DS3897 (Bn)$ $DS008510-3$ FIGURE 1. Driver Output Low Voltage Test $(CD) OV \xrightarrow{t_{DLHC}} t_r \xrightarrow{t_r} t_r$	1.5 V ← ^t DH 1.55 10% ← ^t F	IL V		

· •

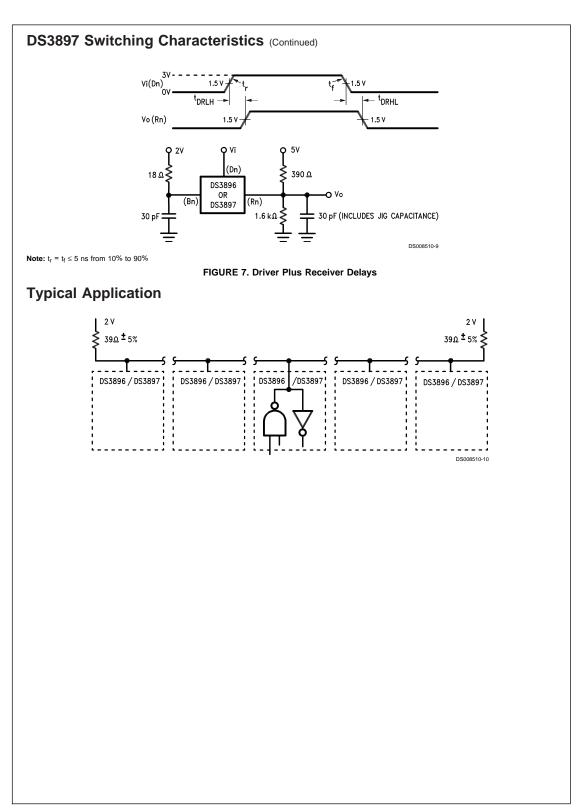


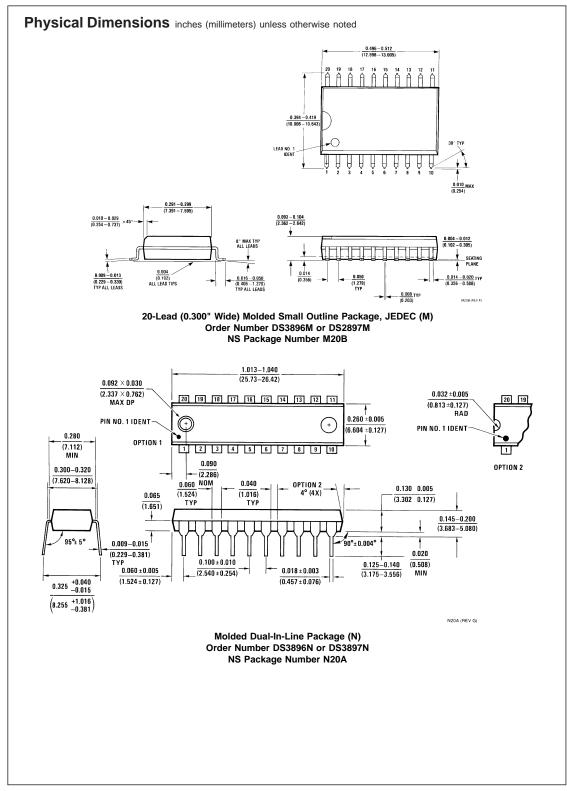
www.national.com



www.national.com

6





	Notes	5		DS3896/DS3897
				1/96
				DS3
				BTL
				Trapezoidal
				oid
				Transceivers
				iceiv
				vers
LIFE SUPPORT POLICY				
DEVICES OR SYSTEMS W	RE NOT AUTHORIZED FOR US ITHOUT THE EXPRESS WRITTE EMICONDUCTOR CORPORATIO	IN APPROVAL OF THE PRESID		
into the body, or (b) su whose failure to perform accordance with instruction	tended for surgical implant pport or sustain life, and n when properly used in ons for use provided in the bly expected to result in a	 A critical component is any support device or system who can be reasonably expected to the life support device or system safety or effectiveness. 	ose failure to perform o cause the failure of	
National Semiconductor Corporation Americas Tel: 1-800-7272-9959 Fax: 1-800-737-7018 Email: support@nsc.com	National Semiconductor Europe Fax: +49 (0) 1 80-530 85 86 Email: europe.support@nsc.com Deutsch Tel: +49 (0) 1 80-530 85 85 English Tel: +49 (0) 1 80-532 93 58 Italiano Tel: +49 (0) 1 80-532 93 58 Italiano Tel: +49 (0) 1 80-532 41 68 0	National Semiconductor Asia Pacific Customer Response Group Tel: 65-2544466 Fax: 65-2504466 Email: sea.support@nsc.com	National Semiconductor Japan Ltd. Tel: 81-3-5639-7560 Fax: 81-3-5639-7507	-

National does not assume any responsibility for use of any circuitry described, no circuit patent licenses are implied and National reserves the right at any time without notice to change said circuitry and specifications.